

## DFR10A20CT/DFR10A40CT/DFR10A60CT



10 Ampere Insulated Common Cathode Fast Recovery Half Bridge Rectifiers

## Features

- \* Latest GPP technology with super fast recovery time
- \* Low forward voltage drop

**Pb Free Plating Product** 

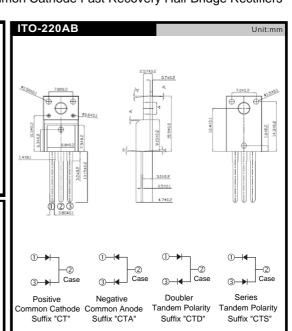
- High current capability
- \* Low reverse leakage current
- \* High surge current capability

Application

- ★ Automotive Inverters and Solar Inverters
- ★ Plating Power Supply, SMPS, EPS and UPS
- \* Car Audio Amplifiers and Sound Device Systems

## **Mechanical Data**

- ★ Case: Fully Isolated Molding TO-220FP
- ★ Epoxy: UL 94V-0 rate flame retardant
- Terminals: Solderable per MIL-STD-202 method 208
- \* Polarity: As marked on diode body
- ★ Mounting position: Any
- ★ Weight: 2.0 gram approximately



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOL	DFR10A20CT	DFR10A40CT	DFR10A60CT	UNIT
Maximum Recurrent Peak Reverse Voltage	Vrrm	200	400	600	V
Maximum RMS Voltage	VRMS	140	280	420	V
Maximum DC Blocking Voltage	VDC	200	400	600	V
Maximum Average Forward Rectified Current Tc=100°C	IF(AV)	10.0			A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)	IFSM	100			A
Maximum Instantaneous Forward Voltage @ 5.0 A	VF	0.98	1.3	1.7	V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	5.0 100			uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35			nS
Typical junction Capacitance (Note 2)	CJ	65			pF
Typical Thermal Resistance (Note 3)	Rejc	2.2			°C/W
Operating Junction and Storage Temperature Range	TJ, TSTG	-55 to +150			°C

NOTES : (1) Reverse recovery test conditions  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{TT} = 0.25A$ .

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

(3) Thermal Resistance junction to case.



